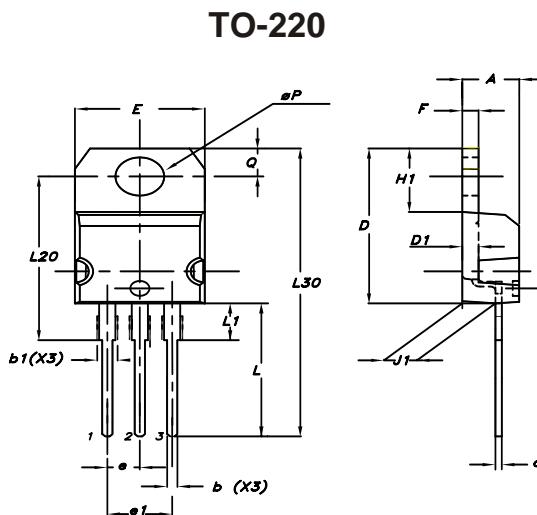
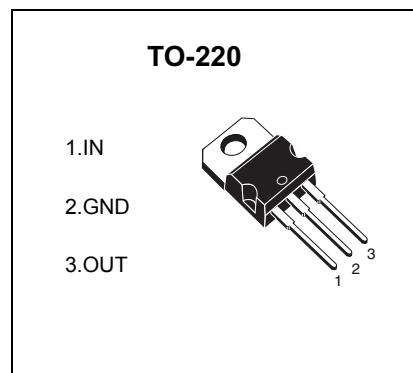


Features

- Output current up to 1.5 A
- Output voltages of - 5; - 8; - 12; - 15 V
- Thermal overload protection
- Short circuit protection
- Output transition SOA protection



Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
ØP	3.75		3.85
Q	2.65		2.95

Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _I	DC input voltage	-35	V
		-40	
I _O	Output current	Internally limited	
P _D	Power dissipation	Internally limited	
T _{STG}	Storage temperature range	-65 to 150	°C
T _{OP}	Operating junction temperature range	0 to 150	°C

Note: Absolute maximum ratings are those values beyond which damage to the device may occur.
Functional operation under these condition is not implied.

Thermal data

Symbol	Parameter	D ² PAK	TO-220	TO-220FP	Unit
R _{thJC}	Thermal resistance junction-case	3	5	5	°C/W
R _{thJA}	Thermal resistance junction-ambient	62.5	50	60	°C/W

L79XX

Electrical Characteristics ($T_c = 25^\circ C$) of 7905 (refer to the test circuits, $T_J = -0$ to $125^\circ C$ $V_I = -10V$, $I_O = 500 \text{ mA}$, $C_I = 2.2 \mu F$, $C_O = 1.0 \mu F$ unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	$T_J = 25^\circ C$	-4.8	-5	-5.2	V
V_O	Output voltage	$I_O = -5 \text{ mA} \text{ to } -1 \text{ A}$, $P_O \leq 15 \text{ W}$ $V_I = -8 \text{ to } -20 \text{ V}$	-4.75	-5	-5.25	V
$\Delta V_O^{(1)}$	Line regulation	$V_I = -7 \text{ to } -25 \text{ V}$, $T_J = 25^\circ C$			100	mV
		$V_I = -8 \text{ to } -12 \text{ V}$, $T_J = 25^\circ C$			50	
$\Delta V_O^{(1)}$	Load regulation	$I_O = 5 \text{ mA} \text{ to } 1.5 \text{ A}$, $T_J = 25^\circ C$			100	mV
		$I_O = 250 \text{ to } 750 \text{ mA}$, $T_J = 25^\circ C$			50	
I_d	Quiescent current	$T_J = 25^\circ C$			3	mA
ΔI_d	Quiescent current change	$I_O = 5 \text{ mA} \text{ to } 1 \text{ A}$			0.5	mA
		$V_I = -8 \text{ to } -25 \text{ V}$			1.3	
$\Delta V_O/\Delta T$	Output voltage drift	$I_O = 5 \text{ mA}$		-0.4		mV/ $^\circ C$
eN	Output noise voltage	$B = 10\text{Hz} \text{ to } 100\text{kHz}$, $T_J = 25^\circ C$		100		μV
SVR	Supply voltage rejection	$\Delta V_I = 10 \text{ V}$, $f = 120\text{Hz}$	54	60		dB
V_d	Dropout voltage	$I_O = 1 \text{ A}$, $T_J = 25^\circ C$, $\Delta V_O = 100 \text{ mV}$		1.4		V
I_{sc}	Short circuit current			2.1		A

- Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics ($T_c = 25^\circ C$) of 7908 (refer to the test circuits, $T_J = -0$ to $125^\circ C$ $V_I = -14V$, $I_O = 500 \text{ mA}$, $C_I = 2.2 \mu F$, $C_O = 1.0 \mu F$ unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V_O	Output voltage	$T_J = 25^\circ C$	-7.7	-8	-8.3	V
V_O	Output voltage	$I_O = -5 \text{ mA} \text{ to } -1 \text{ A}$, $P_O \leq 15 \text{ W}$ $V_I = -11.5 \text{ to } -23 \text{ V}$	-7.6	-8	-8.4	V
$\Delta V_O^{(1)}$	Line regulation	$V_I = -10.5 \text{ to } -25 \text{ V}$, $T_J = 25^\circ C$			160	mV
		$V_I = -11 \text{ to } -17 \text{ V}$, $T_J = 25^\circ C$			80	
$\Delta V_O^{(1)}$	Load regulation	$I_O = 5 \text{ mA} \text{ to } 1.5 \text{ A}$, $T_J = 25^\circ C$			160	mV
		$I_O = 250 \text{ to } 750 \text{ mA}$, $T_J = 25^\circ C$			80	
I_d	Quiescent current	$T_J = 25^\circ C$			3	mA
ΔI_d	Quiescent current change	$I_O = 5 \text{ mA} \text{ to } 1 \text{ A}$			0.5	mA
		$V_I = -11.5 \text{ to } -25 \text{ V}$			1	
$\Delta V_O/\Delta T$	Output voltage drift	$I_O = 5 \text{ mA}$		-0.6		mV/ $^\circ C$
eN	Output noise voltage	$B = 10\text{Hz} \text{ to } 100\text{kHz}$, $T_J = 25^\circ C$		175		μV
SVR	Supply voltage rejection	$\Delta V_I = 10 \text{ V}$, $f = 120\text{Hz}$	54	60		dB
V_d	Dropout voltage	$I_O = 1 \text{ A}$, $T_J = 25^\circ C$, $\Delta V_O = 100 \text{ mV}$		1.1		V
I_{sc}	Short circuit current			1.5		A

- Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

L79XX

Electrical Characteristics (T_c=25°C of 7912 (refer to the test circuits, T_J = -0 to 125°C VI = -19V, I_O = 500 mA, CI = 2.2 μF, CO = 1.0 μF unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _O	Output voltage	T _J = 25°C	-11.5	-12	-12.5	V
V _O	Output voltage	I _O = -5 mA to -1 A, P _O ≤ 15 W V _I = -15.5 to -27 V	-11.4	-12	-12.6	V
ΔV _O ⁽¹⁾	Line regulation	V _I = -14.5 to -30 V, T _J = 25°C			240	mV
		V _I = -16 to -22 V, T _J = 25°C			120	
ΔV _O ⁽¹⁾	Load regulation	I _O = 5 mA to 1.5 A, T _J = 25°C			240	mV
		I _O = 250 to 750 mA, T _J = 25°C			120	
I _d	Quiescent current	T _J = 25°C			3	mA
ΔI _d	Quiescent current change	I _O = 5 mA to 1 A			0.5	mA
		V _I = -15 to -30 V			1	
ΔV _O /ΔT	Output voltage drift	I _O = 5 mA		-0.8		mV/°C
eN	Output noise voltage	B = 10Hz to 100kHz, T _J = 25°C		200		μV
SVR	Supply voltage rejection	ΔV _I = 10 V, f = 120Hz	54	60		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25°C, ΔV _O = 100 mV		1.1		V
I _{sc}	Short circuit current			1.5		A

- Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

Electrical Characteristics (T_c=25°C of 7915 (refer to the test circuits, T_J = -0 to 125°C VI = -23V, I_O = 500 mA, CI = 2.2 μF, CO = 1.0 μF unless otherwise specified).

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
V _O	Output voltage	T _J = 25°C	-14.4	-15	-15.6	V
V _O	Output voltage	I _O = -5 mA to -1 A, P _O ≤ 15 W V _I = -18.5 to -30 V	-14.3	-15	-15.7	V
ΔV _O ⁽¹⁾	Line regulation	V _I = -17.5 to -30 V, T _J = 25°C			300	mV
		V _I = -20 to -26 V, T _J = 25°C			150	
ΔV _O ⁽¹⁾	Load regulation	I _O = 5 mA to 1.5 A, T _J = 25°C			300	mV
		I _O = 250 to 750 mA, T _J = 25°C			150	
I _d	Quiescent current	T _J = 25°C			3	mA
ΔI _d	Quiescent current change	I _O = 5 mA to 1 A			0.5	mA
		V _I = -18.5 to -30 V			1	
ΔV _O /ΔT	Output voltage drift	I _O = 5 mA		-0.9		mV/°C
eN	Output noise voltage	B = 10Hz to 100kHz, T _J = 25°C		250		μV
SVR	Supply voltage rejection	ΔV _I = 10 V, f = 120Hz	54	60		dB
V _d	Dropout voltage	I _O = 1 A, T _J = 25°C, ΔV _O = 100 mV		1.1		V
I _{sc}	Short circuit current			1.3		A

- Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.

RATING AND CHARACTERISTIC CURVES (L78XX)

Figure 1: Dropout Voltage vs Junction Temperature

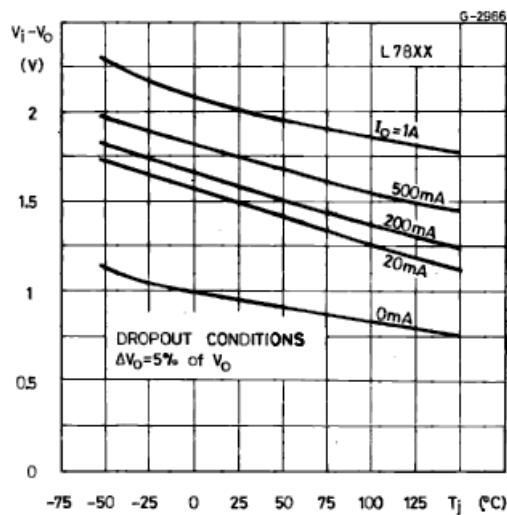


Figure 3: Supply Voltage Rejection vs Frequency Temperature

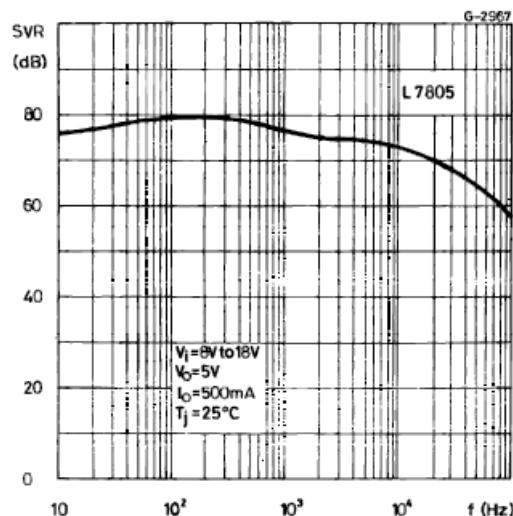


Figure 5: Output Voltage vs Junction Temperature

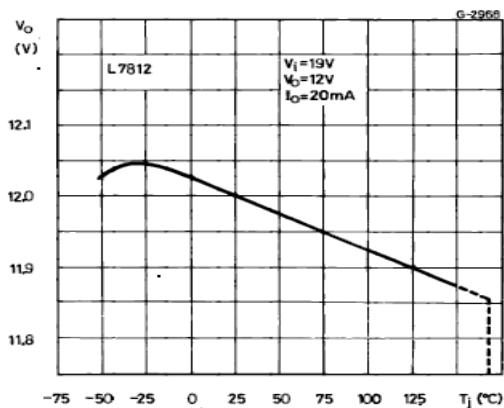


Figure 2: Peak Output Current vs Input/output Differential Voltage

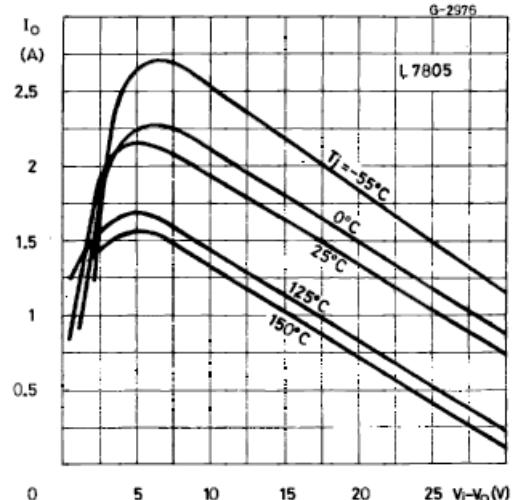


Figure 4: Quiescent Current vs Junction Temperature

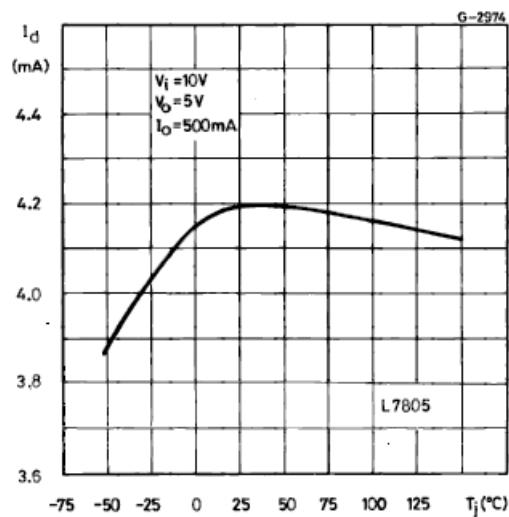
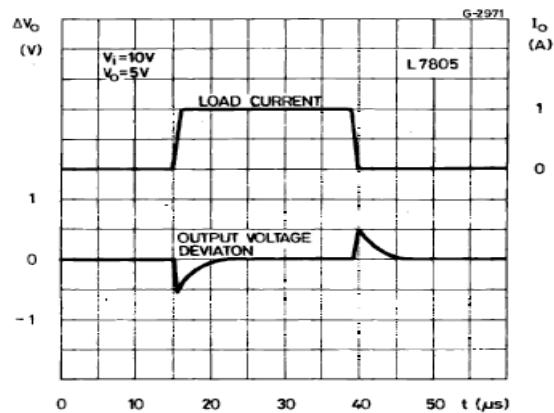


Figure 6: Load Transient Response



RATING AND CHARACTERISTIC CURVES (L78XX)

Figure 7: Output Impedance vs Frequency

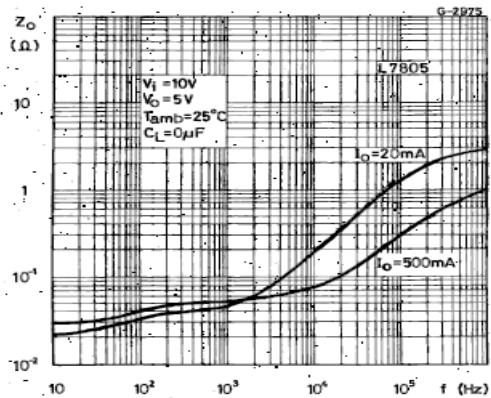


Figure 8: Line Transient Response

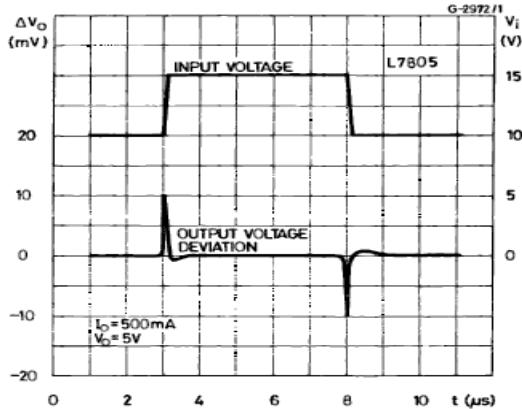


Figure 9: Quiescent Current vs Input Voltage

